

Over-voltage Protection Thyristor

SP2000EC

ROHS

Description

P Series solid state protection thyristor protect telecommunications equipment such as modems, line cards, fax machines, and other CPE.

P Series solid state protection devices are used to enable equipment to meet various regulatory requirements including GR 1089, ITU K. 20, K. 21 and K. 45, IEC 60950, UL 60950, and TIA-968 (formerly known as FCC Part 68).

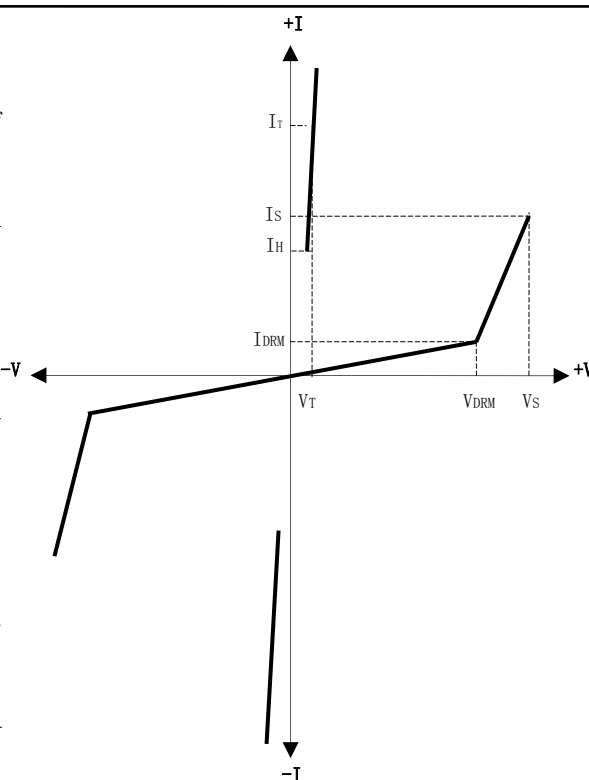
Electrical Parameters

Compared to surge suppression using other technologies, P Series devices offer absolute surge protection regardless of the surge current available and the rate of applied voltage (dv/dt). P Series devices:

- Cannot be damaged by voltage
- Eliminate hysteresis and heat dissipation typically found with clamping devices
- Eliminate voltage overshoot caused by fast-rising transients
- Are non-degenerative
- Will not fatigu
- Have low capacitance, making them ideal for high-speed transmission equipment

Electrical Parameters

Parameter	Definition
C_0	Off-state Capacitance — typical capacitance measured in off state
di/dt	Rate of Rise of Current — maximum rated value of the acceptable rate of rise in current over time
I_S	Switching Current — maximum current required to switch to on state
I_{DRM}	Leakage Current — maximum peak off-state current measured at V_{DRM}
I_H	Holding Current — minimum current required to maintain on state
I_{PP}	Peak Pulse Current — maximum rated peak impulse Current
I_T	On-state Current — maximum rated continuous on-state current
I_{TSM}	Peak One-cycle Surge Current — maximum rated one-cycle AC current
V_S	Switching Voltage — maximum voltage prior to switching to on state
V_{DRM}	Peak Off-state Voltage — maximum voltage that can be applied while maintaining off state
V_F	On-state Forward Voltage — maximum forward voltage measured at rated on-state current
V_T	On-state Voltage — maximum voltage measured at Rated on-state current



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Electrical Characteristics

Part Number	V _{DRM} Volts	V _s Volts	V _T Volts	I _{DRM} μ Amps	I _s mAmps	I _T Amps	I _H mAmps	C _o pF
SP2000EC	180	220	4	5	800	2.2	150	85

* For surge ratings, see table below.


Notes:

- All measurements are made at an ambient temperature of 25°C. I_{PP} applies to -40°C through +85°C temperature range.
- Off-state capacitance (C_o) is measured at 1 MHz with a 2 V bias and is typical value.

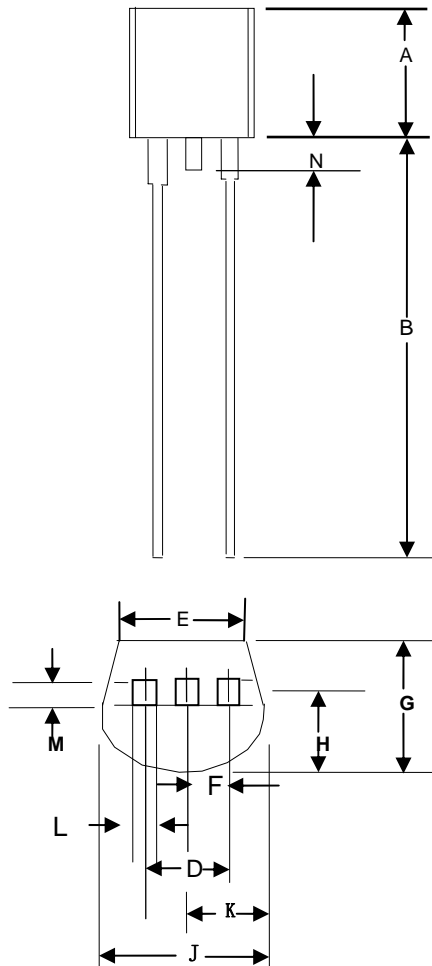
Surge Ratings

Series	I _{PP} 2/10 μ s Amps	I _{PP} 8/20 μ s Amps	I _{PP} 10/160 μ s Amps	I _{PP} 10/560 μ s Amps	I _{PP} 10/1000 μ s Amps	I _{TSM} 60 Hz Amps	di/dt Amps/μ s
C	500	400	200	150	100	50	500

Thermal Considerations

Package	T0-92	Symbol	Parameter	Value	Unit
		T _J	Operating Junction Temperature	-40 to +150	°C
		T _S	Storage Temperature Range	-40 to +150	°C
		R _{θJA}	Junction to Ambient on printed circuit	90	°C/W

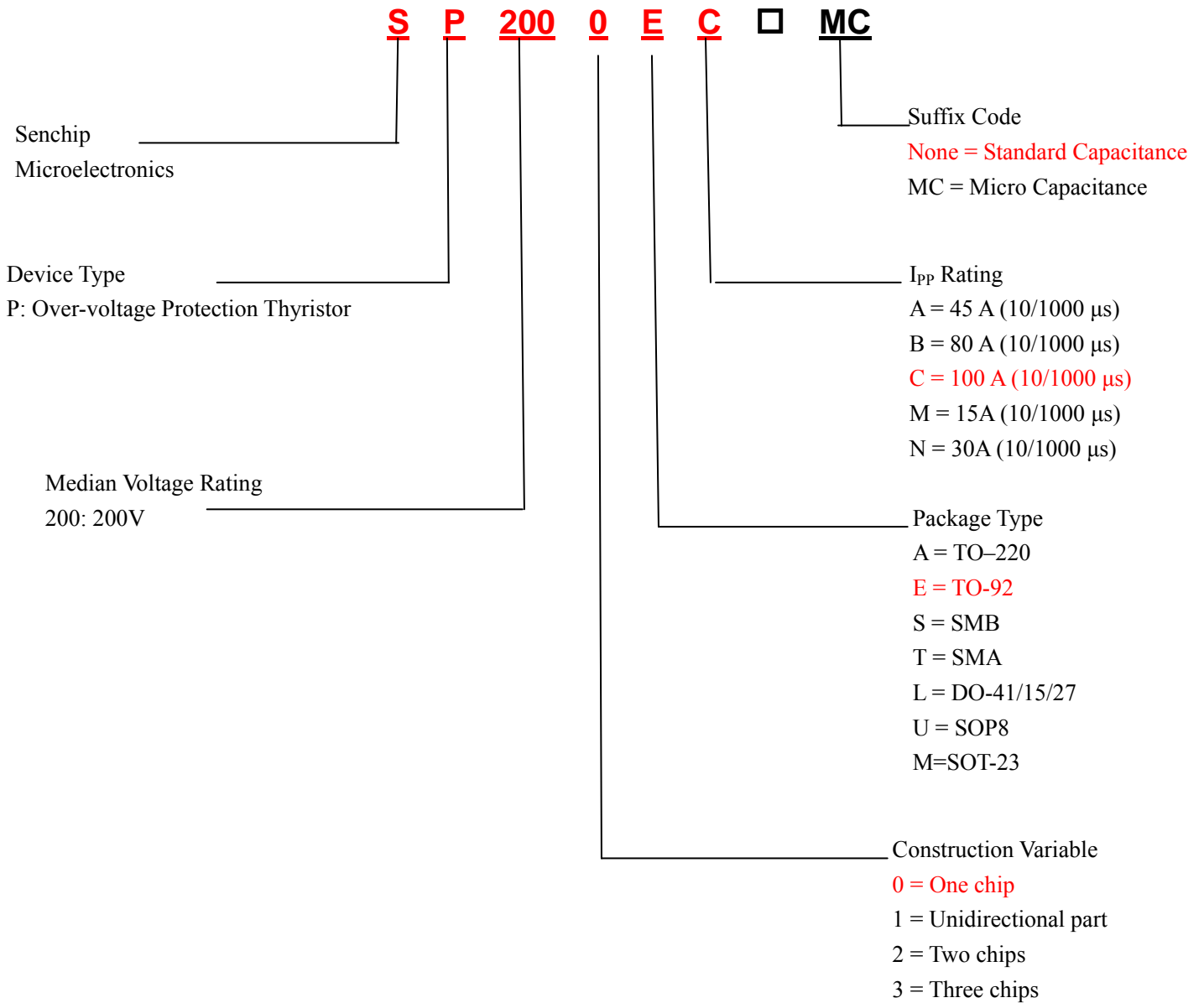
Dimensions



Dimension	Inches		Millimeters	
	MIN	MIN	MIN	MIN
A	0.176	0.196	4.47	4.98
B	0.5		12.7	
D	0.095	0.105	2.14	2.67
E	0.15		3.81	
F	0.046	0.054	1.16	1.37
G	0.135	0.145	3.43	3.68
H	0.088	0.096	2.23	2.44
J	0.176	0.186	4.47	4.73
K	0.088	0.096	2.23	2.44
L	0.013	0.019	0.33	0.48
M	0.013	0.017	0.33	0.43
N		0.06		1.52

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Description of Part Number

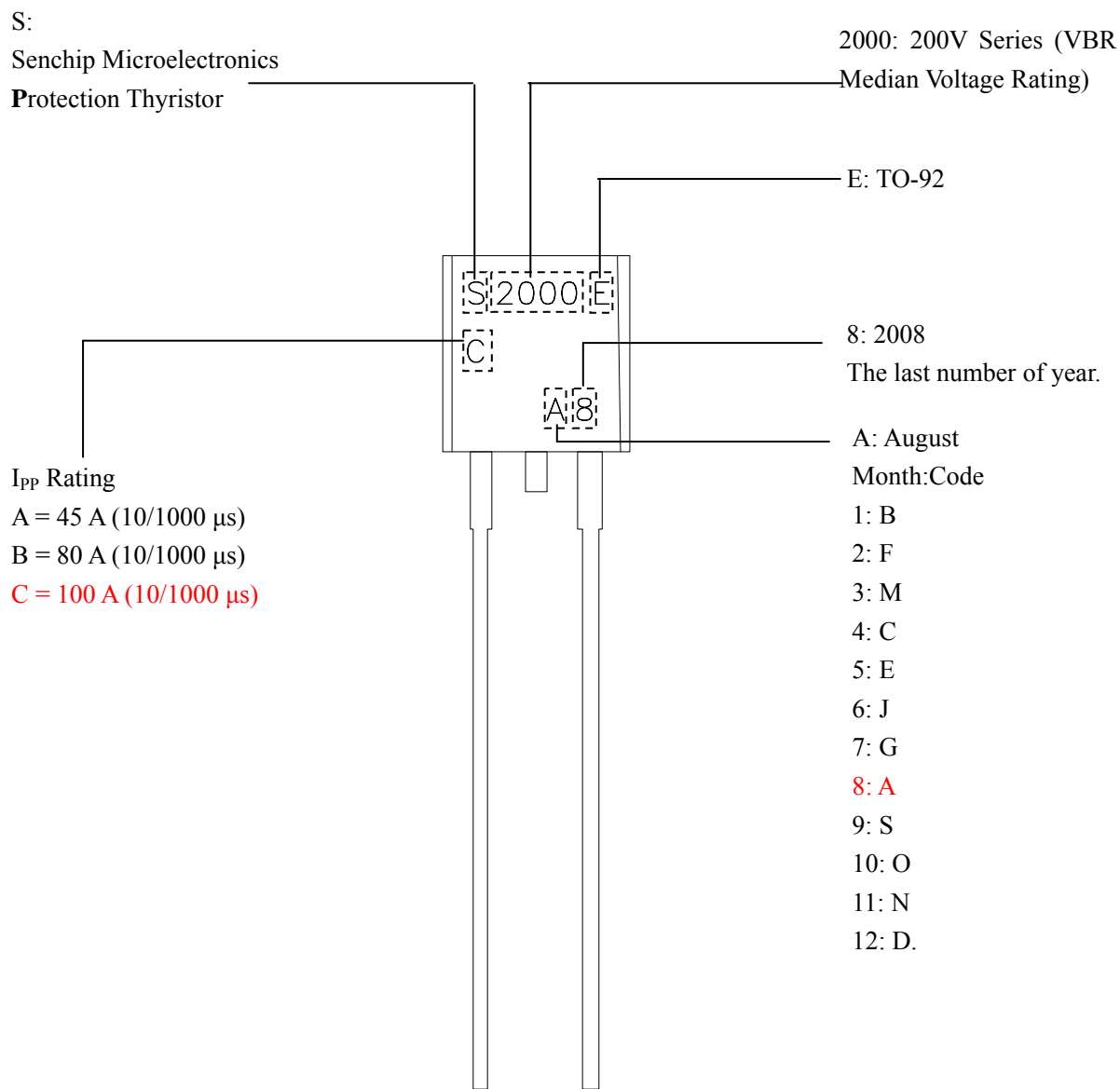


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Description of Marking



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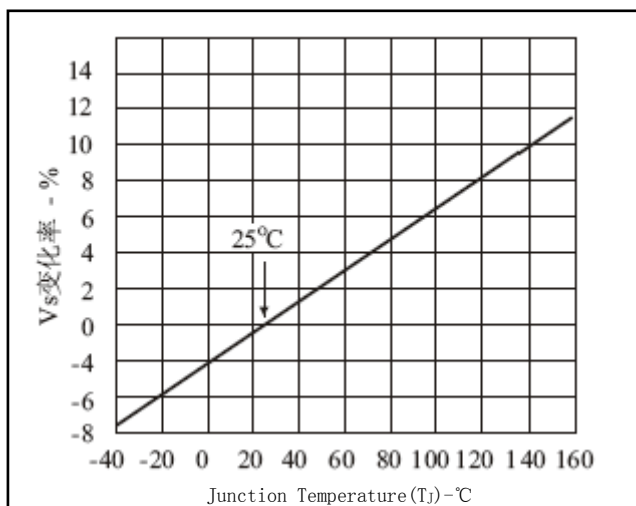
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Summary of Packing Options

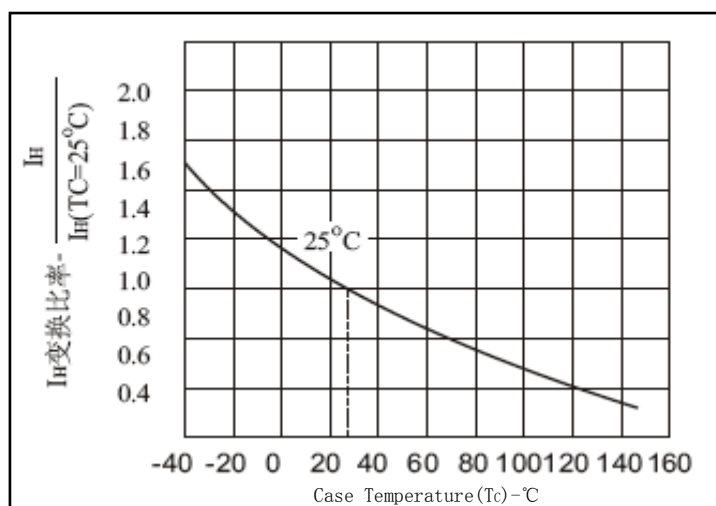
Package Type	Description	Packing Quantity	Industry Standard
T0-92 EA, EB, EC	Bulk Pack	2000 PCS	N/A



Thermal Derating Curves



Normalized VS Change versus Junction Temperature



Normalized DC Holding Current versus Case Temperature



E313687